

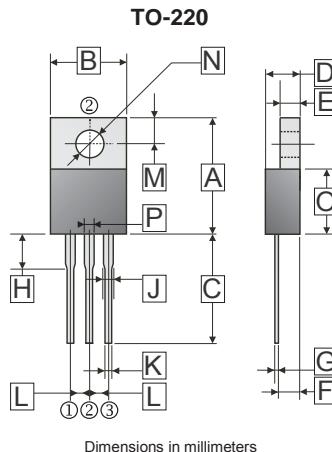
RoHS Compliant Product  
A suffix of "-C" specifies halogen free

## FEATURES

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

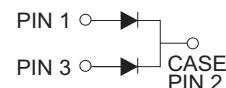
## MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any
- Weight: 2.24 grams (approximate)



Dimensions in millimeters

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.22	16.51	J	1.09	1.78
B	9.65	10.67	K	0.38	1.02
C	12.50	14.75	L	2.39	2.69
D	3.56	4.90	M	2.50	3.43
E	0.51	1.45	N	3.10	4.09
F	2.03	2.92	O	8.38	9.65
G	0.31	0.76	P	0.89	1.45
H	3.6	4.5			



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, de-rate current by 20%.)

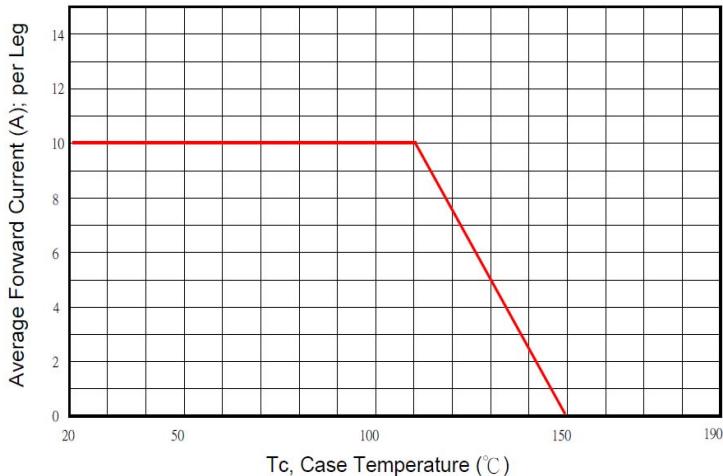
Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	200	V
Working Peak Reverse Voltage	V <sub>RSM</sub>	200	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	200	V
Maximum Average Forward Rectified Current	I <sub>F</sub>	10	A
Per Device	I <sub>F</sub>	20	
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	180	A
Maximum Instantaneous Forward Voltage	V <sub>F</sub>	0.92	V
I <sub>F</sub> =10A, T <sub>A</sub> =25°C, per leg	V <sub>F</sub>	0.8	
Maximum DC Reverse Current at Rated DC Blocking Voltage <sup>4</sup>	I <sub>R</sub>	0.02	mA
T <sub>A</sub> = 25°C	I <sub>R</sub>	5	
T <sub>A</sub> = 100°C			
Typical Junction Capacitance <sup>1</sup>	C <sub>J</sub>	250	pF
Typical Thermal Resistance <sup>2</sup>	R <sub>θJC</sub>	4	°C / W
Typical Thermal Resistance <sup>3</sup>	R <sub>θJA</sub>	10	°C / W
Voltage Rate Of Change (Rated V <sub>R</sub> )	dv / dt	10000	V / μs
Operating Temperature Range T <sub>J</sub>	T <sub>J</sub>	-50~150	°C
Storage Temperature Range T <sub>STG</sub>	T <sub>STG</sub>	-65~175	°C

Notes:

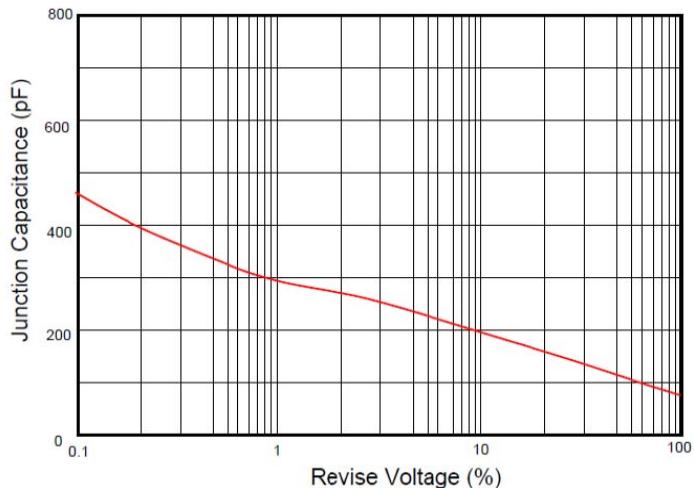
1. Measured at 1MHz and applied reverse voltage of 5.0V D.C.
2. Thermal Resistance Junction to Case.
3. Thermal Resistance Junction to Ambient.
4. Pulse test: 300μs pulse width, 1% duty cycle.

## RATINGS AND CHARACTERISTIC CURVES

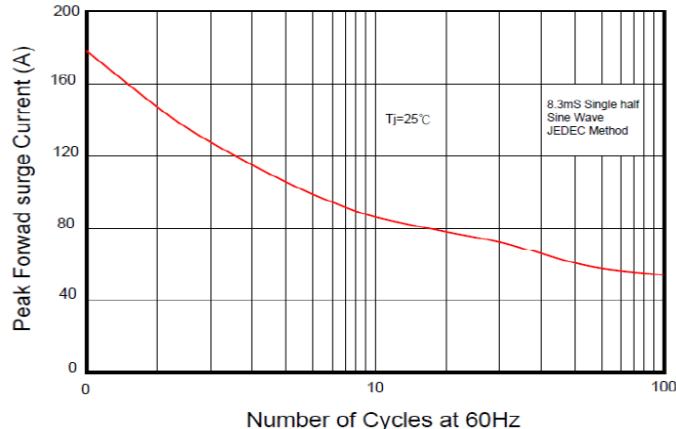
Typical Forward Current Derating Curve



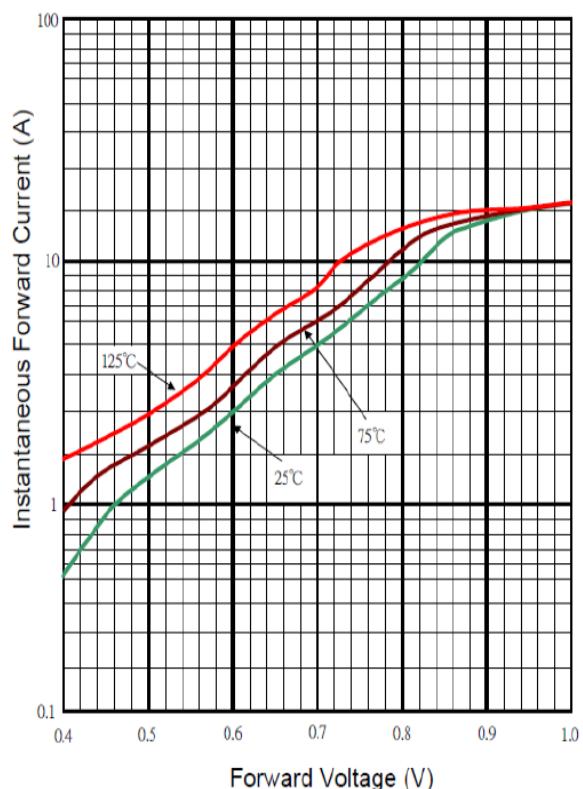
Typical Junction Capacitance



Maximum Non-Repetitive Forward Surge Current



Typical Forward Characteristic



Typical Reverse Characteristic

